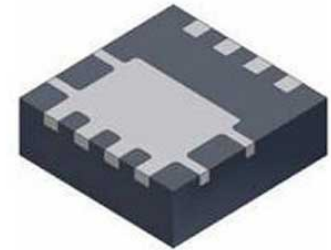


Power Field-Effect Transistor, 7A I(D), 40V, 0.02Ω, 2Element, N-Channel, Silicon, Metal-oxide Semiconductor FET, MO-229, 3 X 3MM, ROHS COMPLIANT, POWER 33, MLP, 8Pin

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	8-PowerWDFN
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FDMC8032L or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

This device includes two 40V N-Channel MOSFETs in a dual Power 33 (3 mm X 3 mm MLP) package. The package is enhanced for exceptional thermal performance.

## Features

100% Rg Tested

## Application

ONSEMI

## Related Products



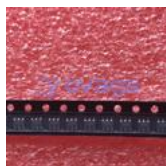
### [FDC645N](#)

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### [FDC6305N](#)

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